



AF
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(NE)
2/B
9-15-99
T. Flowers

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Appln. Of: Hiroaki YOKOYAMA

Serial No.: 08/992,767

Filed: December 17, 1997

For: CONTACT STRUCTURE IN SEMICONDUCTOR INTEGRATED ...

Group: 2814

Examiner: D. Wille

DOCKET:
NEC 19654

The Honorable Commissioner of Patents & Trademarks
Washington, D.C. 20231

AMENDMENT B UNDER RULE 116

Dear Sir:

This Amendment is being filed in response to the Official Action mailed May 25, 1999. Please amend the application as follows:

IN THE SPECIFICATION:

Page 5, line 16, after "included" insert --in--.

IN THE CLAIMS:

Please amend claim 1 as follows:

1. (Twice Amended) A semiconductor device including both a large-diameter contact hole and a small-diameter contact hole formed to penetrate through an insulator film formed on a conductive portion to reach said conductive portion, said small-

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